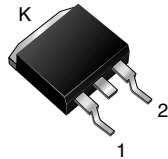


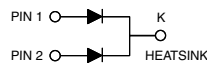
## Dual Low-Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low  $V_F = 0.33\text{ V}$  at  $I_F = 10\text{ A}$

TMBS®  
TO-263AB



VBT6045C



### FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Not recommended for PCB bottom side wave mounting
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC



RoHS  
COMPLIANT

### TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

### PRIMARY CHARACTERISTICS

$I_{F(AV)}$	2 x 30 A
$V_{RRM}$	45 V
$I_{FSM}$	320 A
$V_F$ at $I_F = 30\text{ A}$	0.47 V
$T_J$ max.	150 °C

### MECHANICAL DATA

**Case:** TO-263AB

Molding compound meets UL 94 V-0 flammability rating  
Base P/N-E3 - RoHS compliant, commercial grade

**Terminals:** Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

**Polarity:** As marked

**Mounting Torque:** 10 in-lbs maximum

### MAXIMUM RATINGS ( $T_A = 25\text{ °C}$ unless otherwise noted)

PARAMETER	SYMBOL	VBT6045C	UNIT
Maximum repetitive peak reverse voltage	$V_{RRM}$	45	V
Maximum average forward rectified current (fig. 1)	$I_{F(AV)}$	per device	60
		per diode	30
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	$I_{FSM}$	320	A
Operating junction and storage temperature range	$T_J, T_{STG}$	- 40 to + 150	°C

ELECTRICAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MIN.	UNIT
Instantaneous forward voltage per diode	I <sub>F</sub> = 10 A	T <sub>A</sub> = 25 °C	V <sub>F</sub> <sup>(1)</sup>	0.44	-	V
	I <sub>F</sub> = 15 A			0.47	-	
	I <sub>F</sub> = 30 A			0.54	0.64	
	I <sub>F</sub> = 10 A	T <sub>A</sub> = 125 °C		0.33	-	
	I <sub>F</sub> = 15 A			0.37	-	
	I <sub>F</sub> = 30 A			0.47	0.56	
Reverse current per diode	V <sub>R</sub> = 45 V	T <sub>A</sub> = 25 °C	I <sub>R</sub> <sup>(2)</sup>	-	3000	μA
		T <sub>A</sub> = 125 °C		18	50	mA

Notes

(1) Pulse test: 300 μs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)				
PARAMETER		SYMBOL	VBT6045C	UNIT
Typical thermal resistance	per diode	R <sub>θJC</sub>	1.5	°C/W
	per device		0.8	

ORDERING INFORMATION (Example)					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
TO-263AB	VBT6045C-E3/4W	1.38	4W	50/tube	Tube
TO-263AB	VBT6045C-E3/8W	1.38	8W	800/reel	Tape and reel

RATINGS AND CHARACTERISTICS CURVES

(T<sub>A</sub> = 25 °C unless otherwise noted)

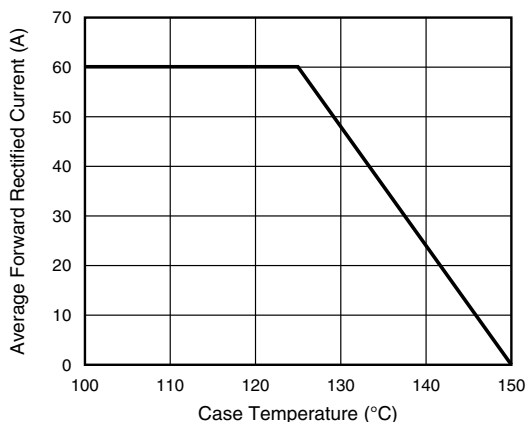


Fig. 1 - Maximum Forward Current Derating Curve

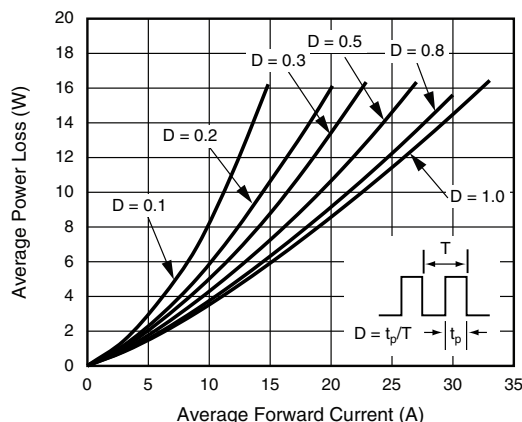


Fig. 2 - Forward Power Loss Characteristics Per Diode

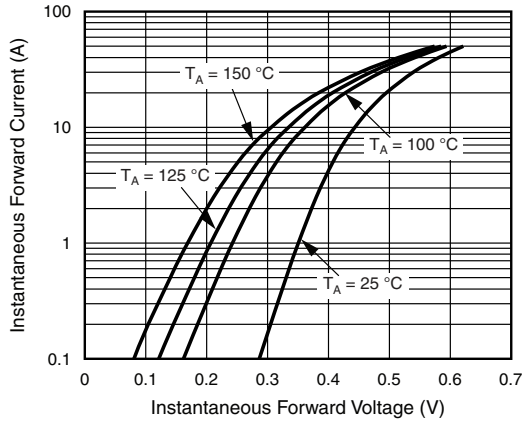


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

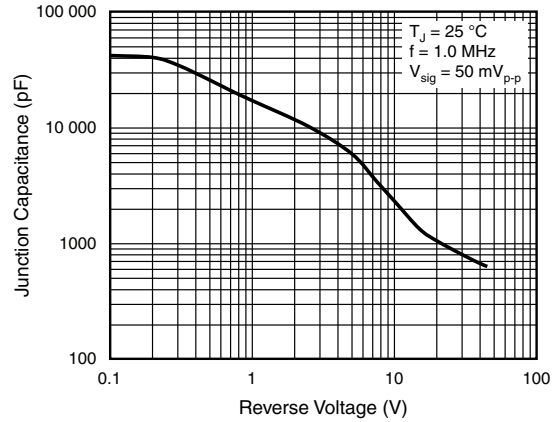


Fig. 5 - Typical Junction Capacitance Per Diode

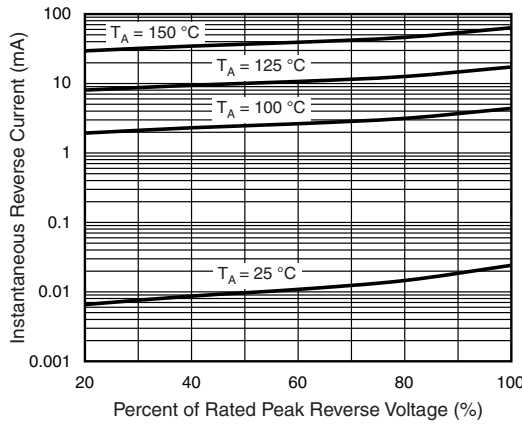


Fig. 4 - Typical Reverse Characteristics Per Diode

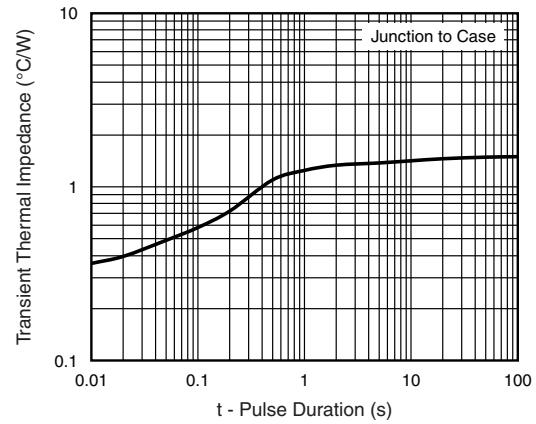
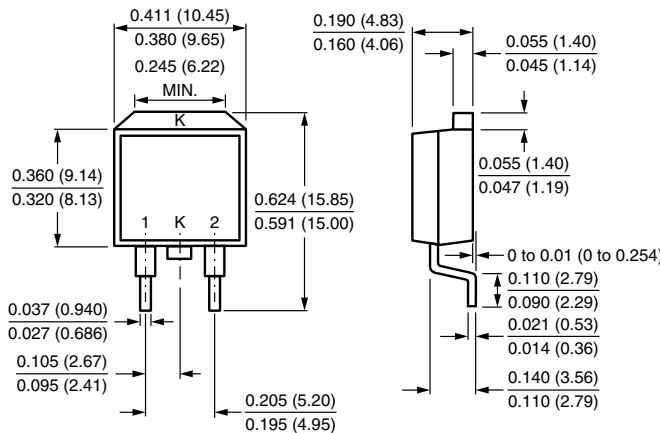


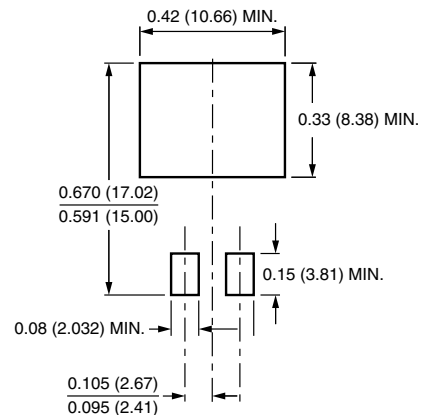
Fig. 6 - Typical Transient Thermal Impedance Per Diode

**PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)

**TO-263AB**



**Mounting Pad Layout**





## Disclaimer

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